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ZXTP25015DFH 15V, SOT23, PNP medium power transistor

Summary

 $BV_{CEO} > -15V$

 $BV_{ECO} > -3V$

 $I_{C(cont)} = -4A$

 $R_{CE(sat)} = 33m\Omega$

V_{CE(sat)} < -55mV @ 1A

 $P_{D} = 1.25W$

Complementary part number ZXTN25015DFH



Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

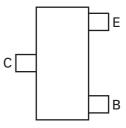
B C

Features

- · High power dissipation SOT23 package
- · High peak current
- · Low saturation voltage
- · 15V forward blocking voltage
- · 3V reverse blocking voltage

Applications

- · MOSFET and IGBT gate driving
- · DC DC converters
- · Motor drive
- · High side driver
- · Load disconnect switch



Pinout - top view

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel		
ZXTP25015DFHTA	7	8	3,000		

Device marking

1A7

Absolute maximum ratings

Parameter	Symbol	Limit	Unit	
Collector-base voltage	V _{CBO}	-15	V	
Collector-emitter voltage	V _{CEO}	-15	V	
Emitter-collector voltage (reverse blocking)	V _{ECO}	-3	V	
Emitter-base voltage	V _{EBO}	-7	V	
Continuous collector current ^(b)	I _C	-4	Α	
Base current	I _B	-1	Α	
Peak pulse current	I _{CM}	-10	Α	
Power dissipation at T _{amb} =25°C ^(a)	P _D	0.73	W	
Linear derating factor		5.84	mW/°C	
Power dissipation at T _{amb} =25°C ^(b)	P _D	1.05	W	
Linear derating factor		8.4	mW/°C	
Power dissipation at T _{amb} =25°C ^(c)	P _D	1.25	W	
Linear derating factor		9.6	mW/°C	
Power dissipation at T _{amb} =25°C ^(d)	P _D	1.81	W	
Linear derating factor		14.5	mW/°C	
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C	

Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient ^(a)	$R_{\Theta JA}$	171	°C/W
Junction to ambient ^(b)	$R_{\Theta JA}$	119	°C/W
Junction to ambient ^(c)	$R_{\Theta JA}$	100	°C/W
Junction to ambient ^(d)	$R_{\Theta JA}$	69	°C/W

NOTES:

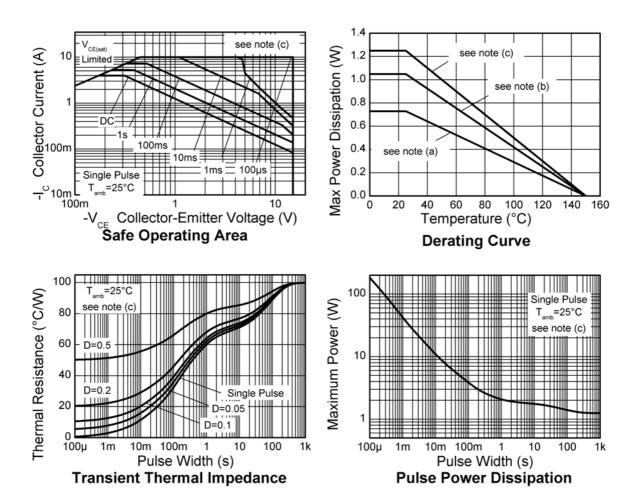
⁽a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

⁽b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

⁽c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

⁽d) As (c) above measured at t<5secs.

Characteristics



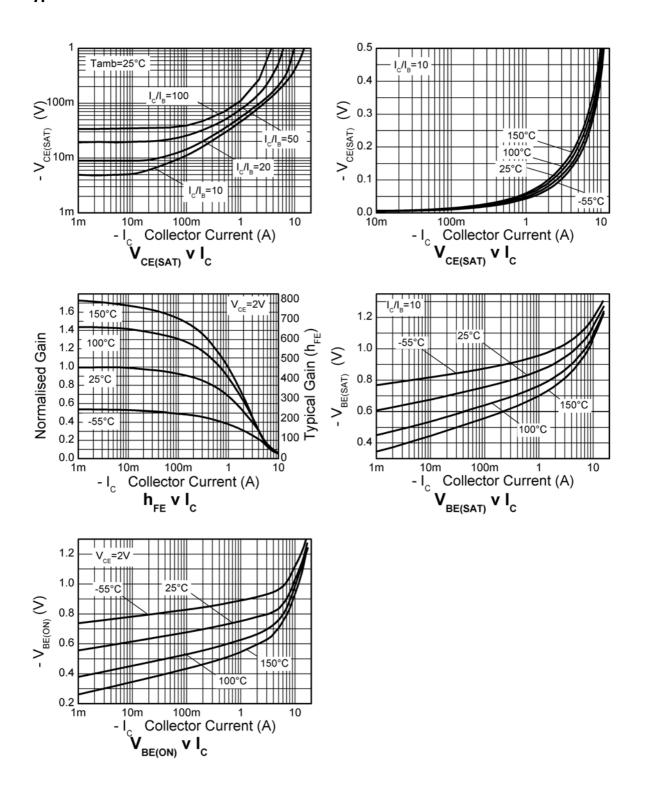
Electrical characteristics (at T_{amb} = 25°C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions		
Collector-base breakdown voltage	BV _{CBO}	-15	-35		V	$I_C = -100 \mu A$		
Collector-emitter breakdown voltage (base open)	BV _{CEO}	-15	-30		V	I _C = -10mA ^(*)		
Emitter-base breakdown voltage	BV _{EBO}	-7	-8.4		٧	I _E = -100μA		
Emitter-collector breakdown voltage (base open)	BV _{ECO}	-3	-8.2		V	$I_E = -100 \mu A^{(*)}$		
Collector-base cut-off current	I _{CBO}		<-1	-50 -20	nA μA	$V_{CB} = -12V$ $V_{CB} = -12V$, $T_{amb} = 100$ °C		
Emitter-base cut-off current	I _{EBO}		<-1	-50	nA	V _{EB} = -5.6V		
Collector-emitter saturation	V _{CE(sat)}		-45	-55	mV	$I_C = -1A$, $I_B = -100 \text{mA}^{(*)}$		
voltage			-110	-150	mV	$I_C = -1A$, $I_B = -10mA^{(*)}$		
			-130	-175	mV	$I_C = -2A$, $I_B = -40 \text{mA}^{(*)}$		
			-160	-210	mV	$I_C = -4A$, $I_B = -200 \text{mA}^{(*)}$		
			-165	-220	mV	$I_C = -5A$, $I_B = -500 \text{mA}^{(*)}$		
Base-emitter saturation voltage	V _{BE(sat)}		-930	-1050	mV	$I_C = -4A$, $I_B = -200 \text{mA}^{(*)}$		
Base-emitter turn-on voltage	V _{BE(on)}		-810	-900	mV	$I_C = -4A$, $V_{CE} = -2V^{(*)}$		
Static forward current transfer ratio	h _{FE}	300	450	900		$I_C = -10 \text{mA}, V_{CE} = -2V^{(*)}$		
Tallo		200	315			$I_C = -1A$, $V_{CE} = -2V^{(*)}$		
		90	145			$I_C = -4A$, $V_{CE} = -2V^{(*)}$		
			30			$I_C = -10A$, $V_{CE} = -2V^{(*)}$		
Transition frequency	f _T		295		MHz	I _C = -50mA, V _{CE} = -10V f = 100MHz		
Output capacitance	C _{OBO}		25	30	pF	V _{CB} = -10V, f = 1MHz ^(*)		
Delay time	t _d		33.8		ns	V _{CC} = -15V.		
Rise time	t _r		43.5		ns	$I_{C} = -750 \text{mA},$		
Storage time	t _s		196		ns	I _{B1} = I _{B2} = -15mA		
Fall time	t _f		51.7		ns			

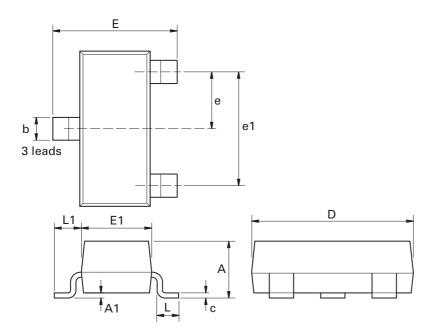
NOTES:

^(*) Measured under pulsed conditions. Pulse width \leq 300 μs ; duty cycle \leq 2%.

Typical characteristics



Package outline - SOT23



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Мах.	Min.	Max.
Α	-	1.12	-	0.044	e1	1.90 NOM		0.075 NOM	
A1	0.01	0.10	0.0004	0.004	Е	2.10	2.64	0.083	0.104
b	0.30	0.50	0.012	0.020	E1	1.20	1.40	0.047	0.055
С	0.085	0.20	0.003	0.008	L	0.25	0.60	0.0098	0.0236
D	2.80	3.04	0.110	0.120	L1	0.45	0.62	0.018	0.024
е	0.95 NOM		0.037 NOM		-	-	-	-	-

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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